NSN 5961-01-605-1786

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Features Provided:
High frequency
Special Features:
Advantages are avalanche voltage rated for reliable operation; soft reverse recovery for low emi/rfi; low irm reduces: -power dissipation
within the diode, -turn-on loss in the commutating switch; planar passivated chips; very short recovery time; extremely low switching losses;
soft recovery behaviour
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0